

1.31 µm SOA (Chip Carrier Type) AA3T115FYB

The AA3T115FYB is 1.31 μ m high gain and low polarization dependent gain SOA (Semiconductor Optical Amplifier) chip on carrier. The SOA chip is p-side up mounted on an AlN sub-mount of the size of 1.1 \times 2.0 mm.

FEATURES

• Gain: 17 dB

Polarization Dependent Gain (PDG): 1.0 dB (typ.)

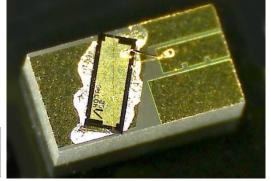
Low Power Consumption: 0.18 WOperating Temperature: 45°C

APPLICATIONS

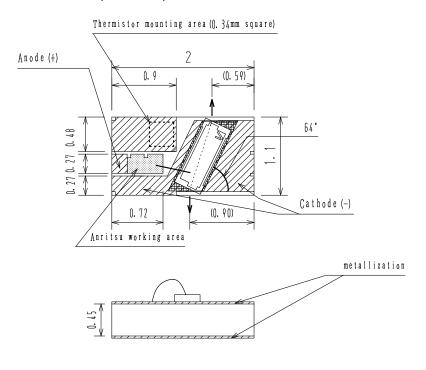
Optical transceiver

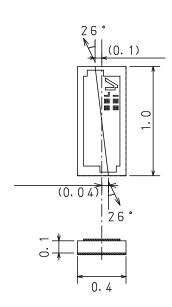
Preamplifier





DIMENSIONS (Unit: mm)





(Enlarged view of the SOA chip)

ABSOLUTE MAXIMUM RATINGS (T_{sub}=25°C)

ltem	Symbol	Rating	Unit	
SOA Forward Current	I _F	350	mA	
SOA Reverse Voltage	se Voltage V _R 2			
Storage Temperature *1	erature *1 T _{stg} -40 to +85		°C	
Process/Soldering Temp. vs Time 300°C 200°C 120°C	-	< 20 < 2 < 100	s hour hour	
ESD (Human Body Model)	ESD	500	V	

^{*}Excess over the absolute maximum ratings may lead to damage.

^{*1} No condensation



OPTICAL AND ELECTRICAL SPECIFICATIONS (T_{sub}=45°C)

ltem	Symbol	Test condition	Min.	Тур.	Max.	Unit
Gain	G	I _F =120 mA, λ _{in} =1310 nm, P _{in} =-25 dBm	16	17	22	dB
Polarization Dependent Gain	PDG	I _F =120 mA, λ _{in} =1310 nm, P _{in} =-25 dBm	-1.5	1	1.5	dB
Saturation Power	P_S	I _F =120 mA, -3 dB, λ _{in} =1310 nm	7	8	10	dBm
Noise Figure	NF	I _F =120 mA, λ _{in} =1310 nm, P _{in} =-25 dBm	6.5	7.5	8.5	dB
Beam Divergence Angle Lateral (Parallel)	θ_t	I _F =120 mA, FAHM	-	22	-	deg.
Beam Divergence Angle Transverse (Perpendicular)	θ_{p}	I _F =120 mA, FAHM	-	31	ı	deg.
Optical output	P _{ASE}	I _F =120 mA	0.5	0.6	1.0	mW
Forward Voltage	V_{F}	I _F =120 mA	1.0	1.2	1.5	V

^{*} The measured data may be different with these specifications depending on the measurement settings. The shipment inspection items include "Gain", "Polarization Dependent Gain", "Saturation Power", "Noise Figure", "ASE output" and "Forward Voltage"; "Beam Divergence Angle" is not inspected.



CAUTION: Handle the fiber of the enclosed device(s) with extreme care; glass fiber is subject to breakage if mishandled and permanent damage to the device may result. Do not pull the device by the fiber or protective sleeve.

Do not coil the fiber into a loop of than 5 mm in

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Please o	contact following local office for the quotation and ord	er.
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catalog	at any time without notice.	

^{*} Hermetic sealing is recommended for long term reliability.